



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#3/D
11/5/2
Sunler

In re Patent Application of)
Shunpei YAMAZAKI et al.)
Serial No. 09/323,692)
Filed: June 2, 1999)
For: ELECTRO-OPTICAL DEVICE)
AND DRIVING METHOD FOR)
THE SAME)

Art Unit: 2815
Examiner: E. Lee

CERTIFICATE OF MAILING

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Washington, D.C. 20231, on 10/28/02

AMENDMENT

Honorable Commissioner of Patents
Washington, D.C. 20231

Sir:

In response to the Office Action dated June 26, 2002 please amend the above-
identified application as follows:

IN THE CLAIMS:

Please amend claims 1, 10, 19, 32, 45 and 68 as follows:

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- DI
1. (Amended) A semiconductor device comprising:
a substrate having an insulating surface;
at least one thin film transistor formed on said insulating surface, said thin
film transistor having a semiconductor layer comprising source, drain and channel
regions;
an insulating film comprising an inorganic material formed on said thin film
transistor;
an organic resin film provided over said insulating film; and
a pixel electrode formed over said organic resin film and connected to said
thin film transistor through an opening provided in said organic resin film,
wherein said semiconductor layer exhibits a peak of Raman spectra,
displaced from a peak of single crystalline silicon to the lower frequency direction,